Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-947-9442

| Inclosure Material:   |
|---|
| Glass   |
| Overall Length:   |
| Between 0.230 inches and 0.300 inches                                       |
| Terminal Length:  |
| 1.000 inches  |
| Overall Diameter:   |
| Between 0.085 inches and 0.107 inches                                       |
| Joint Electronic Device Engineering Council/jedec/case Outline Designation: |
| Do-7  |
| Mounting Method:  |
| Terminal  |
| Features Provided:  |
| Hermetically sealed case  |
| Semiconductor Material:   |
| Silicon   |
| Voltage Rating In Volts Per Characteristic:                                 |
| 30.0 reverse voltage, peak  |
| Current Rating Per Characteristic:  |
| 10.00 milliamperes source cutoff current preset                             |
| Maximum Operating Tempurature Per Measurement Point:                        |
| 150.0 degrees celsius ambient air   |
| Terminal Type And Quantity:   |
| 2 uninsulated wire lead   |
| Specification Data:   |
| 80131-release3453 professional/industrial association specification         |
| Shelf Life:   |
| N/a   |
| Unit Of Measure:  |
|   |
| Demilitarization:   |
| No  |
| Fiig:   |
| A110a0  |
|   |
|   |